



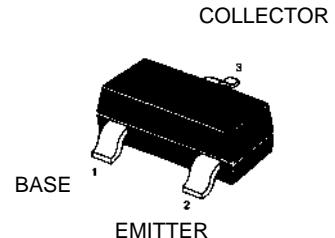
迈拓电子
MAITUO ELECTRONIC

MMBT5551 TRANSISTOR (NPN)

FEATURES

Complementary to MMBT5401

Ideal for medium power amplification and switching



MARKING: G1

SOT-23

MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Value | Units |
|-----------|-------------------------------|---------|-------|
| V_{CBO} | Collector-Base Voltage | 180 | V |
| V_{CEO} | Collector-Emitter Voltage | 160 | V |
| V_{EBO} | Emitter-Base Voltage | 6 | V |
| I_C | Collector Current -Continuous | 0.6 | A |
| P_c | Collector Power Dissipation | 300 | mW |
| T_j | Junction Temperature | 150 | °C |
| T_{stg} | Storage Temperature | -55-150 | °C |

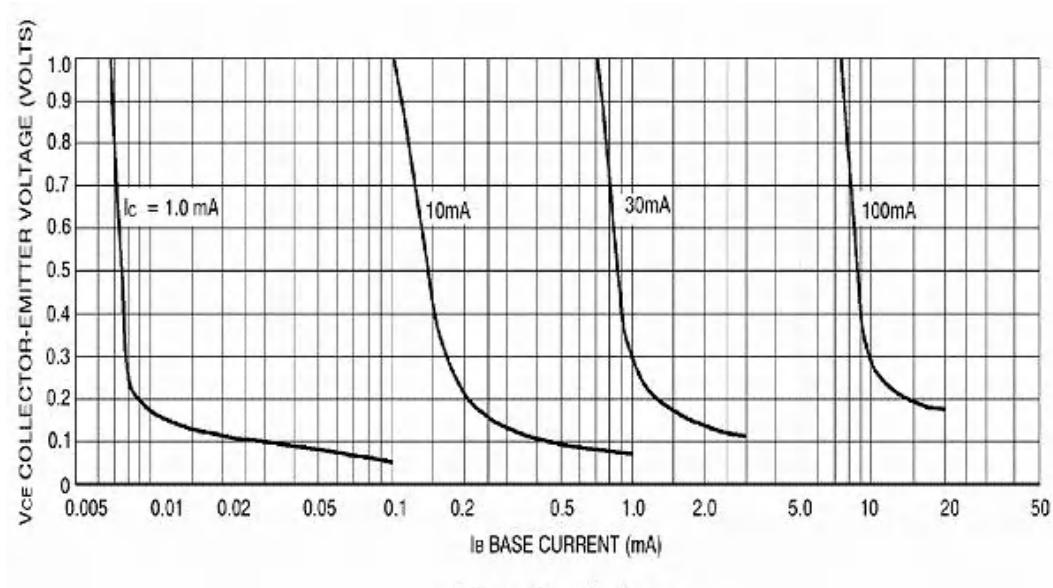
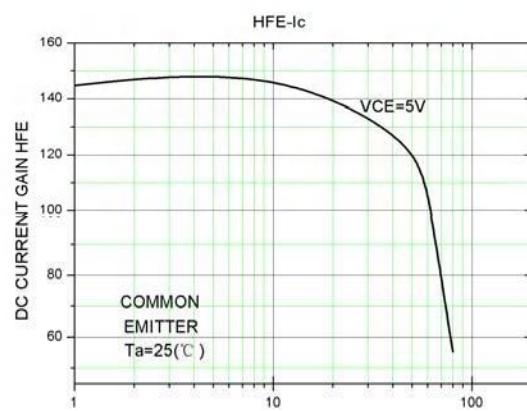
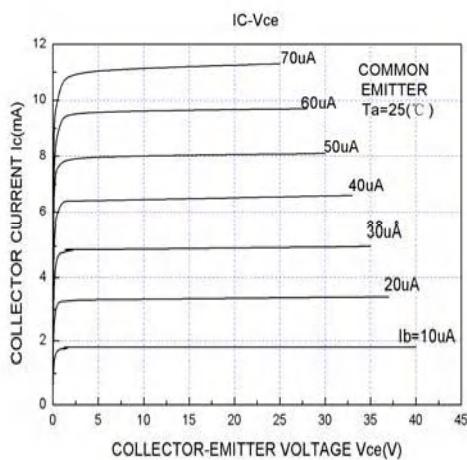
ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

| Parameter | Symbol | Test conditions | MIN | TYP | MAX | UNIT |
|--------------------------------------|-----------------|--|-----|-----|------|------|
| Collector-base breakdown voltage | $V_{(BR)CBO}$ | $I_C=100\mu\text{A}, I_E=0$ | 180 | | | V |
| Collector-emitter breakdown voltage | $V_{(BR)CEO}^*$ | $I_C= 1\text{mA}, I_B=0$ | 160 | | | V |
| Emitter-base breakdown voltage | $V_{(BR)EBO}$ | $I_E= 10\mu\text{A}, I_C=0$ | 6 | | | V |
| Collector cut-off current | I_{CBO} | $V_{CB}= 120\text{V}, I_E=0$ | | | 50 | nA |
| Emitter cut-off current | I_{EBO} | $V_{EB}= 4\text{V}, I_C=0$ | | | 50 | nA |
| DC current gain | h_{FE1}^* | $V_{CE}=5\text{V}, I_C=1\text{mA}$ | 80 | | | |
| | h_{FE2}^* | $V_{CE}=5\text{V}, I_C=10\text{mA}$ | 100 | | 300 | |
| | h_{FE3}^* | $V_{CE}=5\text{V}, I_C=50\text{mA}$ | 50 | | | |
| Collector-emitter saturation voltage | V_{CEsat}^* | $I_C=10\text{mA}, I_B=1\text{mA}$ | | | 0.15 | V |
| | | $I_C=50\text{mA}, I_B=5\text{mA}$ | | | 0.2 | |
| Base-emitter saturation voltage | V_{BEsat}^* | $I_C=10\text{mA}, I_B= 1\text{mA}$ | | | 1 | V |
| | | $I_C=50\text{mA}, I_B= 5\text{mA}$ | | | 1 | |
| Transition frequency | f_T | $V_{CE}=10\text{V}, I_C=10\text{mA}, f=100\text{MHz}$ | 100 | | 300 | MHz |
| Collector output capacitance | C_{ob} | $V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$ | | | 6 | pF |
| Input capacitance | C_{ib} | $V_{BE}=0.5\text{V}, I_C=0, f=1\text{MHz}$ | | | 20 | pF |
| Noise figure | NF | $V_{CE}=5\text{V}, I_C=0.25\text{mA}, f=10\text{Hz to } 15.7\text{KHz}, R_s=1\text{k}\Omega$ | | | 8 | dB |



迈拓电子
MAITUO ELECTRONIC

Typical Characteristics



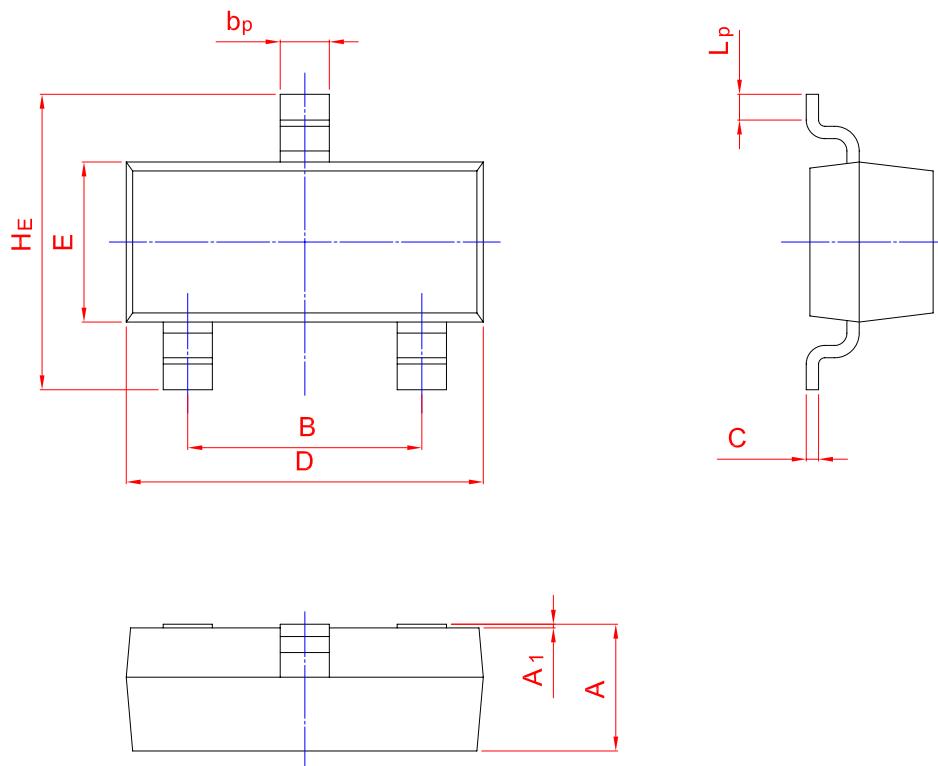


迈拓电子
MAITUO ELECTRONIC

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



| UNIT | A | B | b_p | C | D | E | H_E | A_1 | L_p |
|------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|----------------|--------------|
| mm | 1.40 0.95 | 2.04 1.78 | 0.50 0.35 | 0.19 0.08 | 3.10 2.70 | 1.65 1.20 | 3.00 2.20 | 0.100 0.013 | 0.50 0.20 |